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# An ultra-low loss CaMgGeO<sub>4</sub> microwave dielectric ceramic and its chemical compatibility with silver electrodes for LTCC applications

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#### ABSTRACT

A new ultra-low dielectric loss co-fired CaMgGeO<sub>4</sub> dielectric material with olivine structure was fabricated by the solid-state route. The X-ray patterns, Rietveld refinement, and microstructure revealed the characteristics of the synthesized material. CaMgGeO<sub>4</sub> ceramic belongs to the orthorhombic system with a *Pbmn* space group. Sintered at 1300 °C for 6 h, the ceramic exhibited a densification of 96.5 %, an ultra-high quality factor ( $Q \times f$ ) of 124,900 GHz (tan  $\delta = 1.24 \times 10^{-4}$ ) at a frequency of 15.5 GHz, a permittivity ( $\varepsilon_r$ ) of 6.71, and a temperature coefficient of resonant frequency ( $\tau_f$ ) of -73.7 ppm/°C and the average CTE of CaMgGeO<sub>4</sub> was 12.4 ppm/°C. The sintering temperature of the CaMgGeO<sub>4</sub> ceramic could be reduced from 1300 to 940 °C with the addition of 5wt% B<sub>2</sub>O<sub>3</sub>. The CaMgGeO<sub>4</sub> + 5wt% B<sub>2</sub>O<sub>3</sub> ceramics exhibited favorable microwave dielectric performances:  $Q \times f = 102,000$  GHz (at 16.4 GHz),  $\varepsilon_r = 5.80$ , and  $\tau_f = -64.7$  ppm/°C, respectively. In addition, the CaMgGeO<sub>4</sub> ceramic did not react with Ag electrodes, which could be advantageous in LTCC multilayer microwave devices.

**KEYWORDS:** Microwave dielectric properties, CaMgGeO<sub>4</sub>, LTCC, ultra-low dielectric loss.

#### **INTRODUCTION**

The recent rapid advance in wireless communication systems has encouraged the spread of dielectric materials into diverse applications such as dielectric resonators, filters, substrates, capacitors, oscillators, etc.<sup>1,2</sup> These applications require microwave dielectrics with a low dielectric loss ( $\tan \delta = 1/Q$ ,  $Q \times f$ ; quality factor, f; resonant frequency in microwave region) to achieve a high selectivity and durability in microwave components, a low permittivity  $(\varepsilon_{r})$  to diminish the signal transmission time, and a temperature coefficient of resonant frequency  $(\tau_f)$  close to zero for the stability of the electronic devices in different temperature environments.<sup>3-5</sup> In addition, miniaturization is the required development trend of such materials in order for them to be incorporated into integrated circuits. The miniaturization can be realized by using low-temperature co-fired ceramic (LTCC) technology because LTCC technology can stack ceramics and inner electrodes into a multilayer structure to achieve the required thickness.<sup>6</sup> Silver is usually used as a metal electrode layer due to its high conductivity. Therefore, microwave dielectric ceramics need to be developed to enable LTCC devices with a lower melting point than that of the Ag electrodes (960 °C).<sup>7-9</sup> The traditional method to drop the temperature of ceramics is to add sintering aids, such as glasses or low melting point oxides, although this usually results in the deterioration of the  $Q \times f$  values.<sup>10,11</sup> Recent investigations have suggested that  $B_2O_3$  could dramatically decrease the sintering temperature of ceramics without significantly degrading their performance because B<sub>2</sub>O<sub>3</sub> is easy to evaporate at high temperatures over 900 °C.<sup>12,13</sup>

Germanates with an olivine structure (space group Pbmn) with the general formulas  $Me_2GeO_4$  (Me = Mg, Zn, Ca, Ba) have attracted much interest due to their thermal, mechanical, pyroelectric, and dielectric properties.<sup>14-16</sup> For example, Zn<sub>2</sub>GeO<sub>4</sub> has promising dielectric properties at 1300 °C ( $\varepsilon_r = 6.87$ ,  $Q \times f = 102,700$ GHz,  $\tau_f = -32.4 \text{ ppm/°C}$ ,<sup>17</sup> and Mg<sub>2</sub>GeO<sub>4</sub> sintered at 1250 °C has a low  $\varepsilon_r = 5.48$ , a  $\tau_f$ = -27.61 ppm/°C, and a  $Q \times f = 11,037$  GHz.<sup>18</sup> Nevertheless, the sintering temperature of the above ceramics is too high to co-fire with metallic electrodes or for application in LTCC multilaver devices. In 1995 van Duijn et al.<sup>19</sup> first reported the formation and structure of CaMgGeO<sub>4</sub>, which belongs to the olivine structure with a general formula  $A_2^{2+}B^{4+}O_4^{2-}$ , but the performances of CaMgGeO<sub>4</sub> ceramics at microwave region have not previously been investigated. Here, we report the ultra-low dielectric loss of CaMgGeO<sub>4</sub> ceramic with olivine structure, the method of synthesis, densification process, and microwave dielectric properties. In addition, the influence of B<sub>2</sub>O<sub>3</sub> as a sintering aid on the density, sinterability, and microwave dielectric properties of CaMgGeO<sub>4</sub> is also examined.

#### **EXPERIMENTAL SECTION**

CaMgGeO<sub>4</sub> ceramic specimens were fabricated via the solid-state reaction of high-purity oxides (>99%) CaO, MgO, and GeO<sub>2</sub>. The raw oxides were ball-milled for 6 h using absolute ethanol (CH<sub>3</sub>CH<sub>2</sub>OH,  $\geq$ 99.7%) as an intermediary and the wet oxides were dried at 120 °C. Two-step sintering at 900 °C and 1250 °C for 6 h were employed to obtain CaMgGeO<sub>4</sub>. The CaMgGeO<sub>4</sub> system has a sequence of chemical reaction: CaCO<sub>3</sub>+MgO+GeO<sub>2</sub>  $\xrightarrow{900^{\circ}C}$  CaO+MgO+GeO<sub>2</sub>+CO<sub>2</sub>  $\uparrow$   $\xrightarrow{1250^{\circ}C}$ 

CaMgGeO<sub>4</sub>. The fired powders were milled secondly for 6 hours. The powders were compressed into green disks with 10 mm×5 mm (diameter × thickness) for microwave dielectric measurements mixed with polyvinyl alcohol (5 wt.%) as the binder at a pressure of 200 MPa. The disks were first sintered at 550 °C to burn out the PVA (temperature rate of 1.5 °C/min) and further sintered at 1260-1340 °C with a temperature rate of 5 °C/min.

The crystal structure and phase purity of CaMgGeO<sub>4</sub> were analyzed by X-ray diffractometer (X'Pert PRO, Netherlands). The Rietveld analysis was performed on the XRD pattern using the FullProf program. The microstructure images were studied by scanning electron microscopy (JSM6380-LV, Japan) and the Archimedes principle was used to measure the density of ceramics. The  $\varepsilon_r$ ,  $Q \times f$ , and  $\tau_f$  were measured at microwave frequency by a vector network analyzer (10 MHz-40 GHz, N5230A, Agilent, USA) and an oven (9039, USA) in the temperature range of 25-85 °C. The  $\tau_f$  was calculated by Equation (1):

$$\tau_f = \frac{f_2 - f_1}{f_1 (T_2 - T_1)} \tag{1}$$

In the equation,  $f_1$  and  $f_2$  denote the resonant frequencies at temperatures  $T_1$  (25 °C) and  $T_2$  (85 °C). The linear coefficient of thermal expansion (CTE) of the CaMgGeO<sub>4</sub> ceramic was estimated utilizing Thermal Dilatometer (DIL402C, NETZSCH, Germany).

#### **RESULTS AND DISCUSSION**

Figure 1(a) gives the XRD pattern of the CaMgGeO<sub>4</sub> sample calcined at 1250 °C for 6 hours. The XRD peaks of the sample matched with the standard JCPDS PDF No.36-1483 and the calcined specimen was a single phase with olivine structure in space group *Pbmn*. The refined cell parameters were a = 11.2491(1) Å, b = 6.4018(6)Å, c = 4.9977(7) Å, and V = 359.9151(0) Å<sup>3</sup>. All atomic coordinates are listed in Table I and the crystal structure of the CaMgGeO<sub>4</sub> sample is depicted in the inset of Figure 1(b). The Mg occupies a symmetrical center. Ca and Mg occupying factors indicated a complete ordering of these two atoms. There are three different oxygen atoms, and the Ca atoms are connected to four O(1), one O(2), and one O(3). The Mg atoms are connected to two O(1), two O(2), and two O(3). The Ge atoms are coordinated by two O(1), one O(2), and one O(3). This structure is composed of  $[MgO_6]$  octahedra sharing edges with each other to form a chain parallel to [001]. The bands are connected by [CaO<sub>6</sub>] octahedrons and share edges with them. Separate  $[GeO_4]$  tetrahedrons help to connect the chains in the (100) plane.<sup>19</sup>

The Raman spectrum of CaMgGeO<sub>4</sub> between 60 and 1050 cm<sup>-1</sup> is depicted in Figure 2. 36 Raman-active vibration modes  $(11A_g + 7B_{1g} + 11B_{2g} + 7B_{3g})$  were calculated for the olivine structure with the *Pbmn* symmetry according to the group theory. However, only 12 Raman active modes were fitted, which is much lower than the calculated ones because of peak overlapping.<sup>20</sup> The modes below 200 cm<sup>-1</sup> (B<sub>2g</sub>) were assigned to the lattice vibrations caused by cation ions. In B<sub>1g</sub>, clear modes were found at 216 cm<sup>-1</sup>, 371 cm<sup>-1</sup>, and 383 cm<sup>-1</sup>, and the modes 284 cm<sup>-1</sup>, 431 cm<sup>-1</sup> and 475 cm<sup>-1</sup> were assigned as B<sub>3g</sub>. The high-frequency modes at 650-800 cm<sup>-1</sup> (A<sub>g</sub>)

correspond to the stretching modes of the [GeO<sub>4</sub>] tetrahedron.

The SEM pictures recorded on the surfaces of the CaMgGeO<sub>4</sub> ceramics sintered at various temperatures are shown in Figure 3. When sintered from 1260 to 1280 °C, the sample presented a moderately dense microstructure with some pores, as shown in Figure 3(a) and (b). At 1300 °C, the porosity decreased, a dense uniform microstructure was observed and the grain boundaries were clear, as shown in Figure 3(c). However, following further increases of the temperature, it was obvious that grains of abnormal growth and pores were formed, as shown in Figure 3(d) and (e). This was probably due to the excessive sintering temperatures.

Figure 4 exhibits the change of density,  $\varepsilon_r$ ,  $Q \times f$  and  $\tau_f$  values of CaMgGeO<sub>4</sub> ceramics with the sintering temperature. As the sintering temperature increased the relative density gradually increased to the highest value ~ 3.57 g/cm<sup>3</sup> at 1300 °C. The theoretical density of the CaMgGeO<sub>4</sub> ceramic is 3.70 g/cm<sup>3</sup> and so the maximal relative density could reach 96.5 % at 1300 °C. The decrease of density at temperatures over 1300 °C may be due to over-heating and heterogeneous exaggerated grain growth. This was consistent with the changes seen in the SEM images.

As shown in Figure 4(b), the  $\varepsilon_r$  first increased, reached a peak value of 6.71 at 1300 °C and then reduced with rising temperature. Generally, the permittivity at microwave frequencies relies on the densities, any secondary phases, and ionic polarizability, etc.<sup>20,21</sup> In the present work, the effects of second phases and density on

the  $\varepsilon_r$  value may be negligible because the XRD analysis did not detect the second phases and the CaMgGeO<sub>4</sub> ceramic possessed a high density. The theoretical permittivity can be explained by the total of individual ionic polarizability and the molar volume of a compound in accordance with Clausius-Mossotti equation:<sup>22,23</sup>

$$\varepsilon_{ih} = \frac{3V + 8\pi\alpha}{3V - 4\pi\alpha} \tag{2}$$

In the equation, V is the cell volume and  $\alpha$  is the molecular polarizability. The total of ionic polarizability of CaMgGeO<sub>4</sub> could be derived from the equation:

$$\alpha (CaMgGeO_4) = \alpha (Ca^{2+}) + \alpha (Mg^{2+}) + \alpha (Ge^{4+}) + 4\alpha (O^{2+})$$
(3)

where  $\alpha(Ca^{2+})$ ,  $\alpha(Mg^{2+})$ ,  $\alpha(Ge^{4+})$ , and  $\alpha(O^{2+})$  are 3.16 Å<sup>3</sup>, 1.32 Å<sup>3</sup>, 1.63 Å<sup>3</sup> and 2.01 Å<sup>3</sup>, respectively. The  $\varepsilon_{th}$  of CaMgGeO<sub>4</sub> is 6.79, which is extremely close to the measured value. The relative error between  $\varepsilon_r$  and  $\varepsilon_{th}$  for CaMgGeO<sub>4</sub> is 1.17 %, which implies that there is no other mechanism of polarization in the microwave frequency band for CaMgGeO<sub>4</sub> ceramic.<sup>24</sup>

Figure 4(c) demonstrates the relationship between  $Q \times f$  values and temperature of CaMgGeO<sub>4</sub> ceramics. It was observed that the change in the  $Q \times f$  values was similar to the apparent densities with temperature. These variations were considered to relate to the densifications, and the high  $Q \times f$  value usually corresponds to the high densification.<sup>25,26</sup> At the best densification temperature of 1300 °C, the CaMgGeO4 ceramic exhibited an ultra-high  $Q \times f$  value of 124,900 GHz (corresponding to an ultra-low dielectric loss of  $1.24 \times 10^{-4}$ ) at a frequency of 15.5 GHz. Normally, the

factors influencing the dielectric loss could be divided into two major classes: the internal factors largely relying on inharmonic terms in the crystal potential energy, and the external factors correlated to the grain boundaries, density, lattice defects, impurities, etc. Kim *et al.*<sup>27</sup> summarized that the packing fraction of a structure is a key factor affecting  $Q \times f$ . They showed that a rise in packing fraction can reduce the lattice vibrations, producing an increase in the quality factor. In the crystal structure, each ion is considered as a rigid sphere. The ratio of the volume of ions at each site to the total unit cell volume is an effective packing fraction. For CaMgGeO<sub>4</sub> ceramic, the packing fraction may be determined by the equation (4):

packing fraction (%) = 
$$\frac{\text{volume of packed ions}}{\text{volume of unit cell}} \times Z$$
  
=  $\frac{4\pi/3 \times (r_{Ca}^3 + r_{Mg}^3 + r_{Ge}^3 + 4 \times r_o^3)}{V} \times 4$  (4)

In the equation, r is the ionic radius. The calculated packing fraction of CaMgGeO<sub>4</sub> ceramic was 57.76 %.

Within the sintered range of 1260-1340 °C, the  $\tau_f$  values of CaMgGeO<sub>4</sub> ceramic experienced only small changes and remained steady at about -74 ppm/°C (Figure 4(d)). The  $\tau_f$  values were affected by the temperature coefficient of relative permittivity ( $\tau_{\varepsilon}$ ) and the linear thermal expansion coefficient ( $\alpha_L$ ), as the equation (5):<sup>28</sup>

$$\tau_f = -(\frac{\tau_{\varepsilon}}{2} + \alpha_L) \tag{5}$$

Because the  $\alpha_L$  of microwave dielectric ceramic is about 10 ppm/°C,<sup>29</sup> the  $\tau_{\varepsilon}$  value

would play a primary role in CaMgGeO<sub>4</sub> ceramic. Using Equation (2), Bosman and Havinga inferred the formula of  $\tau_{\epsilon}$ :<sup>30,31</sup>

$$\tau_{\varepsilon} = \frac{1}{\varepsilon} \left( \frac{\partial \varepsilon}{\partial T} \right) = \frac{(\varepsilon - 1)(\varepsilon + 2)}{3\varepsilon} (A + B + C)$$
(6)

$$A = \frac{1}{\alpha_m} \left( \frac{\partial \alpha_m}{\partial T} \right)_V$$
  

$$B = \frac{1}{\alpha_m} \left( \frac{\partial \alpha_m}{\partial V} \right)_T \left( \frac{\partial V}{\partial T} \right)_P$$
  

$$C = -\frac{1}{V} \left( \frac{\partial V}{\partial T} \right)_P$$
(7)

where  $\varepsilon$ ,  $\alpha_m$ , and A describe the relative permittivity, polarizability, and direct dependence of the polarizability on temperature, respectively. A is generally negative. The term B is positive and C is negative, and they are also very similar in magnitude. Hence, in CaMgGeO<sub>4</sub> ceramic, a positive (A+B+C) value corresponded to a negative  $\tau_f$  value. Figure 5 shows the CTE curve of CaMgGeO<sub>4</sub> sintered at 1300 °C. The inset of Figure 5 gives the change of CTE with different temperatures and the average CTE of CaMgGeO<sub>4</sub> is 12.4 ppm/°C.

In consideration of the close correlation between  $\tau_f$  and  $\tau_c$  values, it is meaningful to determine the  $\tau_c$  value of CaMgGeO<sub>4</sub> for practical applications and for a further understanding of the  $\tau_f$  value. Figure 6 shows the temperature dependence of  $\varepsilon_r$  and *tan* $\delta$  at four different frequencies (1 kHz, 10 kHz, 100 kHz, and 1 MHz). As seen, in the lower temperature area (from room temperature to 250 °C), both  $\varepsilon_r$  and *tan* $\delta$ exhibited only slight variation with increasing temperature, indicating their temperature stability in this temperature region. However, a remarkable increase in both values with obvious frequency dispersion was observed, which might be due to the increase in conductivity with increasing temperature. The inset of Figure 6 shows the enlarged profile at 25-250 °C measured at 1 MHz, from which  $\tau_{\varepsilon}$  was calculated to be 149 ppm/°C. According to equation (5), the calculated  $\tau_{f}$  value was -86.9 ppm/°C which was close but a little higher than the measured value, ~ -73.7 ppm/°C for CaMgGeO<sub>4</sub>. Notably, the relative permittivity measured at 1 MHz was about 9.15, which was much higher than the value (6.71) measured at microwave frequency. This indicates that in the RF region another polarizability mechanism contributes to the permittivity.

To further lower the densification temperature of the CaMgGeO<sub>4</sub> to below 960 °C, various amounts of B<sub>2</sub>O<sub>3</sub> were added to the CaMgGeO<sub>4</sub> samples. The choice of B<sub>2</sub>O<sub>3</sub> was guided by previous successful applications in lowering the sintering temperature of several materials <sup>32,33</sup>. In the current work 1, 3, 5, and 7 wt.% B<sub>2</sub>O<sub>3</sub> were used to determine the optimum doping content. The bulk densities of CaMgGeO<sub>4</sub> + *x* wt.% B<sub>2</sub>O<sub>3</sub> (*x* = 1, 3, 5, and 7) as a function of sintering temperature are depicted in Figure 7. As observed, B<sub>2</sub>O<sub>3</sub> doping effectively reduced the densification temperature of CaMgGeO<sub>4</sub> ceramic to 1220 °C at 1 wt.% B<sub>2</sub>O<sub>3</sub> and to 940 °C at 5 wt.% B<sub>2</sub>O<sub>3</sub>, and further to 920 °C at 7 wt.% B<sub>2</sub>O<sub>3</sub>, which was much lower than the temperature of pure CaMgGeO<sub>4</sub> + 5 wt.% B<sub>2</sub>O<sub>3</sub> sintered at 940 °C. However, 7 wt.% B<sub>2</sub>O<sub>3</sub> resulted in an apparent decrease in bulk density, which was due to the

appearance of secondary phases, as approved by XRD analysis. Figure 8 gives the XRD patterns of CaMgGeO<sub>4</sub> ceramic with different  $B_2O_3$  additions sintered at their relative densification temperatures for 6 h. By indexing with the JCPDF card, it was clearly observed that the XRD pattern of 1 wt.% B<sub>2</sub>O<sub>3</sub>-added CaMgGeO<sub>4</sub> was very alike to that of the single ceramic but when the  $B_2O_3$  content increased to 3 wt.% and 5 wt.%, an additional peak attributed to an unknown second phase was detected. However, at x = 7, B<sub>2</sub>O<sub>3</sub> (JCPDS NO. 24-0160) and Ca<sub>3</sub>B<sub>2</sub>O<sub>6</sub> (JCPDS NO.26-0885) secondary phases were formed along with the major CaMgGeO<sub>4</sub> phase, suggesting a chemical reaction between CaMgGeO<sub>4</sub> and  $B_2O_3$ . The lower bulk densities of  $B_2O_3$ and Ca<sub>3</sub>B<sub>2</sub>O<sub>6</sub> (2.46 g/cm<sup>3</sup> and 3.11 g/cm<sup>3</sup>, respectively) could explain the relatively low bulk density of CaMgGeO<sub>4</sub> + 7 wt.% B<sub>2</sub>O<sub>3</sub>. These results indicate that appropriate amount  $B_2O_3$  addition can dramatically reduce the sintering temperature of CaMgGeO<sub>4</sub> whereas high-level doping reduces the formation of second phases which would degrade the dielectric performances. Thus, 5 wt.%  $B_2O_3$  was selected as the optimum dosage to reduce the sintering temperature of CaMgGeO<sub>4</sub>.

The microwave dielectric properties, density, and sintering temperature of CaMgGeO<sub>4</sub> + 5wt% B<sub>2</sub>O<sub>3</sub> ceramics are listed in Table II. The 5 wt.% B<sub>2</sub>O<sub>3</sub> added into CaMgGeO<sub>4</sub> ceramic could dramatically reduce the sintering temperature from 1300 to 940 °C, and the material exhibited good microwave dielectric characteristics:  $Q \times f =$  102,000 GHz (at 16.4 GHz),  $\varepsilon_r = 5.80$  and  $\tau_f = -64.7$  ppm/°C. Compared with the parent CaMgGeO<sub>4</sub> ceramic, B<sub>2</sub>O<sub>3</sub> addition induced a slight degradation in the  $Q \times f$  and  $\varepsilon_r$ . As is well-known, the dielectric properties in the microwave frequency region

are sensitive to the influence of extrinsic factors, especially any second phase(s).<sup>34,35</sup> Therefore, the decrease in dielectric performance of the  $B_2O_3$ -added samples could be partly explained by the appearance of the second phase which was detected by the XRD analysis.

For LTCC multilayer microwave device applications the chemical compatibility of CaMgGeO<sub>4</sub> ceramic with silver electrodes should be evaluated. Therefore, a mixture of 5wt% B<sub>2</sub>O<sub>3</sub> added CaMgGeO<sub>4</sub> ceramic powder with 20 wt.% Ag powder was co-fired and examined to identify any potential reactions between them. The XRD patterns, BSE image and EDS analysis of CaMgGeO<sub>4</sub> + 5 wt.% B<sub>2</sub>O<sub>3</sub> + 20 wt.% Ag samples co-fired at 940 °C for 6h are presented in Figure 9. Only diffraction peaks of CaMgGeO<sub>4</sub> and Ag were detected in the XRD patterns. Additionally, the BSE image showed two different kinds of grains with clear boundaries. EDS analysis indicated that the smaller grains included the elements Ca, Mg, Ge and O, and the ratio of Ca:Mg:Ge was nearly 1:1:1. Thus the smaller grains should be the CaMgGeO<sub>4</sub> phase, and the larger grains was Ag. The reason for the larger size of the Ag grains compared to the  $CaMgGeO_4$  ceramic grains might be associated with the difference in the temperature of sintering between pure Ag and CaMgGeO<sub>4</sub> ceramic. Pure silver has a lower sintering temperature, thus when sintered at the same temperature the silver grains could grow faster, leading to the observed larger Ag grains. All the above results imply that CaMgGeO<sub>4</sub> ceramic could be a possibility for applications in LTCC multilayer microwave devices.

Table III gives the dielectric performances of some ultra-low loss dielectric

materials. In contrast,  $Q \times f$  of the present CaMgGeO<sub>4</sub> ceramic is comparable to willemite, forsterites, rock-salt compounds, and the complex perovskite Ba(Zn<sub>1/3</sub>Ta<sub>2/3</sub>)O<sub>3</sub> (BZT), but it is much lower than the complex perovskite Ba(Mg<sub>1/3</sub>Ta<sub>2/3</sub>)O<sub>3</sub> (BMT). It is well known that prolonging heat treatment over 100 hours is essential for BMT and BZT ceramics to achieve good dielectric properties, but this would increase energy consumption in fabrication. Thus, the simple processing, low sintering temperature, and desirable dielectric performances make CaMgGeO<sub>4</sub>-based materials important supplements for the LTCC multilayer device.

#### CONCLUSION

A novel ultra-low dielectric loss co-fired CaMgGeO<sub>4</sub> microwave dielectric material was fabricated by the solid phase sintering route. The XRD and Rietveld refinement indicated that CaMgGeO<sub>4</sub> ceramic belonged to the orthorhombic system with a *Pbmn* space group. The ceramic sintered at 1300 °C/6 h exhibited a density of 96.5 % and an average CTE of 12.4 ppm/°C. The CaMgGeO<sub>4</sub> ceramic possessed excellent microwave properties:  $Q \times f = 124,900$  GHz (tan  $\delta = 1.24 \times 10^{-4}$ , f= 15.5GHz),  $\varepsilon_r = 6.71$ , and  $\tau_f = -73.7$  ppm/°C. The densification temperature of CaMgGeO<sub>4</sub> ceramic could be reduced from 1300 to 940 °C when 5wt% B<sub>2</sub>O<sub>3</sub> was added. CaMgGeO<sub>4</sub> + 5wt% B<sub>2</sub>O<sub>3</sub> ceramics also exhibited good microwave dielectric properties with  $Q \times f = 102,000$  GHz (at 16.4 GHz),  $\varepsilon_r = 5.80$ , and  $\tau_f = -64.7$  ppm/°C. In addition, the chemical compatibility of CaMgGeO<sub>4</sub> with Ag electrodes opens up its application in LTCC technology.

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Ceramic	Atom	Site	x/a	y/b	z/c	Biso.	Occ.
	Ca	4c	0.2242(2)	1/4	0.03624(3)	0.4334(7)	0.5
	Mg	4a	0	0	0	0.4896(7)	0.5
CaMaCaO	Ge	4c	0.4197(7)	1/4	0.07875(1)	0.2272(8)	0.5
CaMgGeO <sub>4</sub>	O(1)	8d	0.34969(2)	1/4	0.23099(4)	0.1731(3)	1
	O(2)	4c	0.05856(4)	1/4	0.23220(6)	1.1751(8)	0.5
	O(3)	4c	0.41093(3)	1/4	0.72671(5)	1.4031(7)	0.5

Table I The atomic coordinates of CaMgGeO<sub>4</sub> and the reliability factors

Table II Sintering temperature, density and microwave dielectric properties of

CaMgGeO <sub>4</sub> + 5wt% B <sub>2</sub> O <sub>3</sub> ceramics sintered at different temper	atures.
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Composition	S.T. (°C)	$\rho$ (g/cm <sup>3</sup> )	$\mathcal{E}_r$	$Q \times f(GHz)$	$\tau_f(\text{ppm/°C})$
CaMgGeO <sub>4</sub>	1300	3.57	6.71	124,900	-73.7
	900	3.55	5.21	82,600	-68.6
	920	3.59	5.43	95,600	-67.0
CaMgGeO <sub>4</sub> +5wt% B <sub>2</sub> O <sub>3</sub>	940	3.62	5.80	102,000	-64.7
	960	3.62	5.56	85,210	-66.5
	980	3.60	5.23	70,880	-64.9

### Table III Ultra-low loss dielectric ceramics and their properties

Ceramics	S.T. (°C)	Crystal Structure	$\mathcal{E}_r$	$Q \times f(GHz)$	τ <sub>f</sub> (ppm/ <sup>o</sup> C)	Reference
CaMgGeO <sub>4</sub>	1300/6h	Orthorhombic <i>Pbmn</i> Olivine	6.71	124,900	-73.7	This work

2 3 4	CaMgGeO <sub>4</sub> +5wt% B <sub>2</sub> O <sub>3</sub>	940/6h	Orthorhombic <i>Pbmn</i> Olivine	5.80	102,000	-64.7	This work
5 6 7	$Z_2O_3$ Zn <sub>2</sub> GeO <sub>4</sub>	1300/4h	Rhombohedral <i>R-3</i>	6.87	102,700	-32.4	[17]
, 8 9 10	Mg <sub>2</sub> GeO <sub>4</sub> +3wt% B <sub>2</sub> O <sub>3</sub>	1250/4h	Orthorhombic <i>Pbmn</i> Olivine	6.76	95,000	-28.7	[18]
11 12 13	Zn <sub>2</sub> SiO <sub>4</sub>	1320/CIP	Rhombohedral <i>R-3</i> Willemite	6.6	219,000	-61	[36]
14 15	Mg <sub>2</sub> SiO <sub>4</sub>	1450/2h	Forsterite	6.8	270,000	-67	[37]
16 17	CaMgSi <sub>2</sub> O <sub>6</sub>	1300/CIP	Monoclinic C12/c1	7.6	121,380	-66	[38]
18 19	Mg <sub>2</sub> TiO <sub>4</sub>	1450/4h	Cubic Fd-3m Spinel	14	150,000	-50	[39]
20 21 22	Li <sub>2</sub> Mg <sub>3</sub> TiO <sub>6</sub>	1280/6h	Cubic <i>Fd-3m</i> Rock-salt	15.2	152,000	-39	[40]
23 24 25	$Li_2Mg_3Ti_{0.9}Ge_{0.1}O_6$	1140/6h	Cubic <i>Fd-3m</i> Rock-salt	13.7	131,500	-34.2	[41]
26 27 28 29	Li <sub>2</sub> Mg <sub>4</sub> TiO <sub>7</sub>	1600/4h	Cubic <i>Fd-3m</i> Rock-salt	13.43	233,600	-7.24	[42]
30 31 32	$Li_4Mg_3Ti_2O_9$	1450/4h	Cubic <i>Fd-3m</i> Rock-salt	15.97	135,800	-7.06	[43]
33 34 35	$Li_6Mg_7Ti_3O_{16}$	1550/4h	Cubic <i>Fd-3m</i> Rock-salt	15.27	209,400	-11.32	[44]
36 37	$Ba(Mg_{1/3}Ta_{2/3})O_3$	1640/100h	Complex perovskite	24	430,000	8	[45]
38 39	Ba(Zn <sub>1/3</sub> Ta <sub>2/3</sub> )O <sub>3</sub>	1350/120h	Complex perovskite	28	168,000	1	[46]
40							

#### **FIGURE CAPTIONS:**

**Figure 1** X-ray diffraction pattern of CaMgGeO<sub>4</sub> calcined at 1250 °C (a), Rietveld refinement of the room temperature XRD data and schematic crystal structure for CaMgGeO<sub>4</sub> (b).

**Figure 2** Raman spectrum of CaMgGeO<sub>4</sub> in the range of 60-1050 cm<sup>-1</sup>.

- **Figure 3** Microstructures of CaMgGeO<sub>4</sub> ceramics sintered at 1260 °C (a), 1280 °C (b), 1300 °C (c), 1320 °C (d), 1340 °C (e).
- **Figure 4** The  $\varepsilon_r$ ,  $Q \times f$  and  $\tau_f$  values of CaMgGeO<sub>4</sub> ceramics as a function of temperature.
- Figure 5 Thermal expansion curve in the temperature range of 25-900 °C of CaMgGeO<sub>4</sub> sintered at 1300 °C.
- **Figure 6** The temperature dependence of relative permittivity ( $\varepsilon_r$ ) and loss tangent (*tan* $\delta$ ) at four different frequencies (1 kHz, 10 kHz, 100 kHz, and 1 MHz).
- **Figure 7** The bulk densities of CaMgGeO<sub>4</sub> ceramic with different B<sub>2</sub>O<sub>3</sub> contents as a function of sintering temperature.
- **Figure 8** XRD patterns of CaMgGeO<sub>4</sub> ceramic with different B<sub>2</sub>O<sub>3</sub> additions sintered at densification temperatures.
- Figure 9 XRD pattern, BSE image and EDS analysis of CaMgGeO<sub>4</sub> + 5wt% B<sub>2</sub>O<sub>3</sub> +20wt% Ag samples co-fired at 940 °C for 6h.

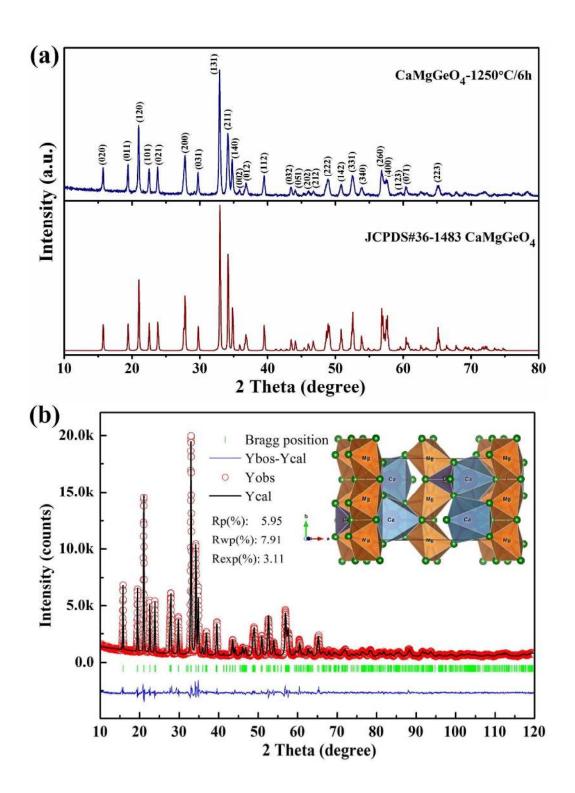


Figure 1

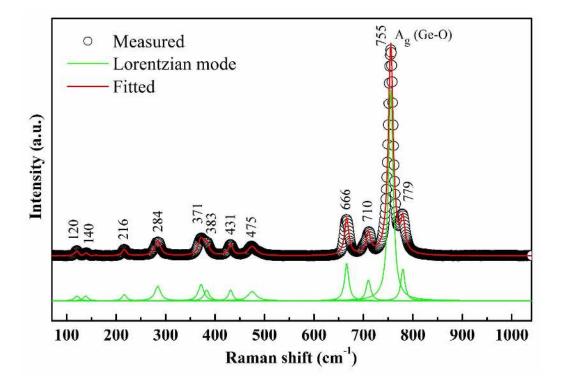


Figure 2

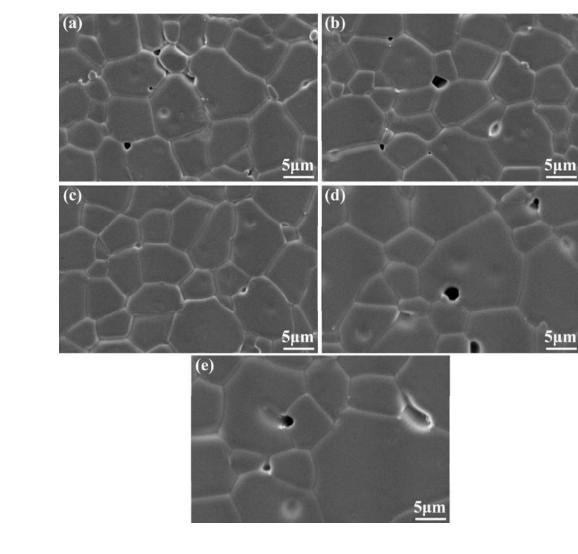


Figure 3

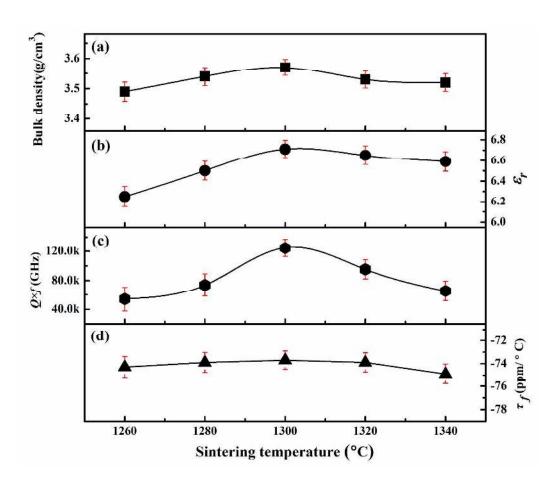


Figure 4

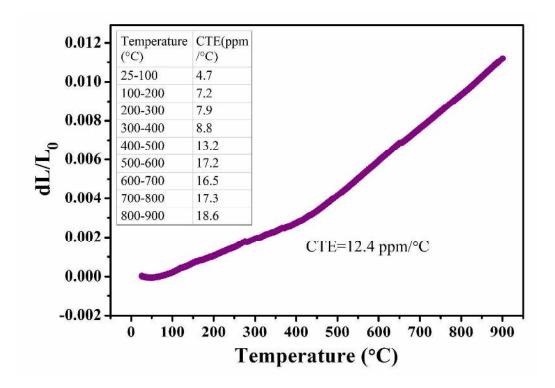


Figure 5

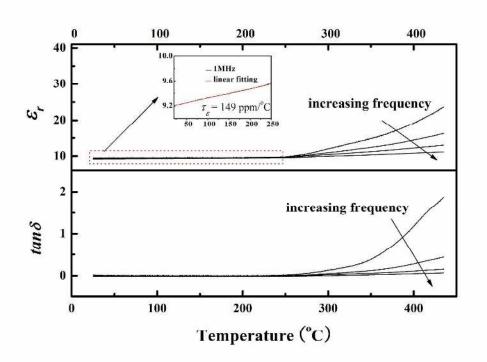


Figure 6

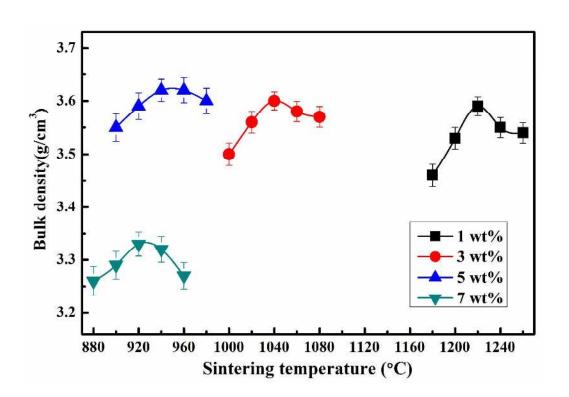


Figure 7

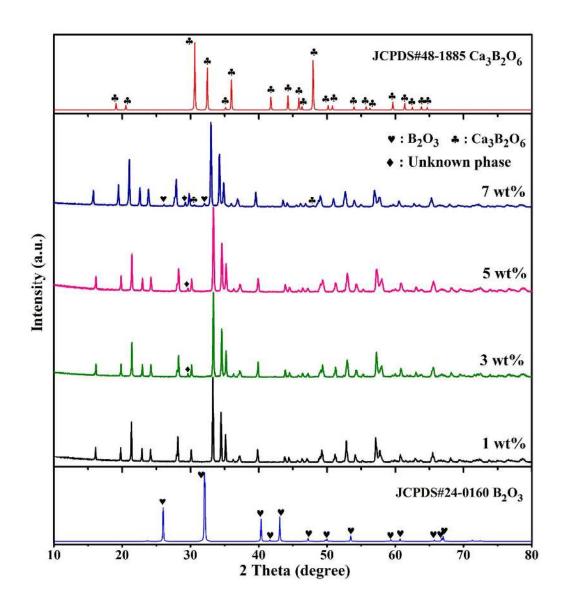


Figure 8

ACS Paragon Plus Environment

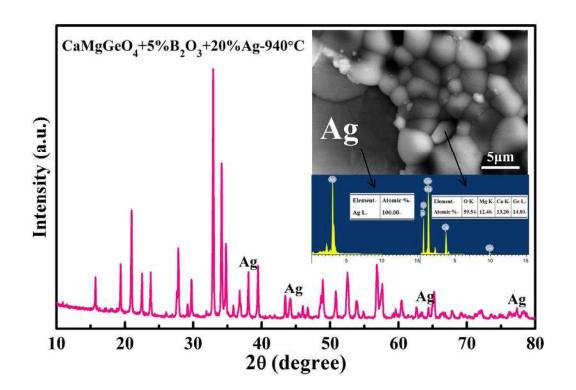
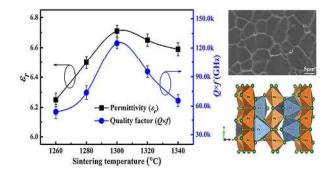


Figure 9

## For Table of Contents Use Only



# Synopsis

Low permittivity and ultra-low dielectric loss make the olivine structural CaMgGeO<sub>4</sub>-based ceramics suitable candidate for substrates and packaging applications.